Diode Semiconductor Device - Page 1 of 1



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Inclosure Material:

Metal

Function For Which Designed:

Rectifier

Mounting Facility Quantity:

1

Mounting Method:

Threaded stud

Features Provided:

Hermetically sealed case

Thread Size:

0.750 inches

Semiconductor Material:

Silicon

Voltage Rating In Volts Per Characteristic:

600.0 repetitive peak reverse voltage

Current Rating Per Characteristic:

300.00 amperes forward current, average

Thread Series Designator:

Unf

Terminal Type And Quantity:

1 insulated wire lead w/terminal lug and 1 threaded stud

Shelf Life:

N/a

Unit Of Measure:

Demilitarization:

No

Fiig:

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